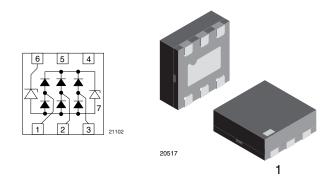
**Vishay Semiconductors** 

# USB-OTG BUS-Port ESD-Protection for V<sub>BUS</sub> = 28 V



### **MARKING** (example only)



Dot = pin 1 marking XX = date code YY = type code (see table below)

### **FEATURES**

- Ultra compact LLP75-7L package
- Low package height < 0.6 mm
- 3-line USB ESD-protection with max. working range = 5.5 V
- V<sub>BUS</sub>-protection with 28 V working range
- Low leakage current
- Low load capacitance C<sub>D</sub> = 0.7 pF
- ESD-protection to IEC 61000-4-2
- ± 15 kV contact discharge ± 15 kV air discharge
- Surge current acc. IEC 61000-4-5 I<sub>PP</sub> > 3 A
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

ORDERING INFORMATION						
DEVICE NAME	CE NAME ORDERING CODE		MINIMUM ORDER QUANTITY			
VBUS053CZ-HAF	VBUS053CZ-HAF-G-08	3000	15 000			

PACKAGE DATA								
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS		
VBUS053CZ-HAF	LLP75-7L	UA	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT				
Data line D+, D-, ID: Pin 1, 2 ar	nd 3 to ground (pin 7)							
Peak pulse current	acc. IEC 61000-4-5; $t_P = 8/20 \ \mu s$ ; single shot	I <sub>PPM</sub>	3	А				
Peak pulse power	acc. IEC 61000-4-5; $t_P = 8/20 \ \mu s$ ; single shot	P <sub>PP</sub>	36	W				
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 15	kV				
	Air discharge acc. IEC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 15	kV				
V <sub>BUS</sub> : Pin 6 to ground (pin 7)								
Peak pulse current	acc. IEC 61000-4-5; $t_P = 8/20 \ \mu s$ ; single shot	I <sub>PPM</sub>	3	А				
Peak pulse power	acc. IEC 61000-4-5; $t_P = 8/20 \ \mu s$ ; single shot	P <sub>PP</sub>	156	W				
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 30	kV				
	Air discharge acc. IEC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 30	kV				
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C				
Storage temperature		T <sub>STG</sub>	- 55 to + 150	°C				

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

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For technical questions, contact: ESDprotection@vishay.com

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RoHS COMPLIANT

GREEN (5-2008)\*\*



# VBUS053CZ-HAF

### Vishay Semiconductors USB-OTG BUS-Port ESD-Protection for $V_{BUS} = 28 \text{ V}$



ELECTRICAL CHARACTERISTICS VBUS053CZ-HAF All inputs (pin 1, 2, and 3) to ground (pin 7)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of line which can be protected	N <sub>channel</sub>	-	-	3	lines	
Reverse working voltage	at I <sub>R</sub> = 0.1 μA	V <sub>RWM</sub>	-	-	5.5	V	
	at V <sub>R</sub> = 3.3 V		-	-	0.02	μA	
Reverse current	at V <sub>R</sub> = 3.3 V; T = 65 °C	I <sub>R</sub>	-	-	0.085	μA	
	at $V_R = V_{RWM} = 5.5 V$		-	-	0.1	μA	
Forward voltage	at I <sub>F</sub> = 15 mA	V <sub>F</sub>	0.7	-	1.2	V	
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	6.5	-	10	V	
	at I <sub>PP</sub> = 1 A; acc. IEC 61000-4-5	V <sub>C</sub>	-	10	12	V	
Reverse clamping voltage	at I <sub>PP</sub> = 3 A; acc. IEC 61000-4-5		-	15	18	V	
Forward clamping voltage	at I <sub>F</sub> = 3 A; acc. IEC 61000-4-5	V <sub>F</sub>	-	3.4	4.1	V	
Line capacitance	Test pin at $V_R = 0 V$ ; any other I/O pin at $V_R = 3.3 V$ ; f = 1 MHz	0	-	0.7	1	pF	
Line to line capacitance	Among pins 1, 2 and 3 at $V_R = 0 V$ ; f = 1 MHz	C <sub>D</sub>	-	0.35	0.5	pF	
Line symmetry	Difference of the line capacitance	dC <sub>D</sub>	-	-	0.1	pF	

#### Note

· Ratings at 25 °C, ambient temperature unless otherwise specified

ELECTRICAL CHARACTERISTICS VBUS053CZ-HAF V <sub>BUS</sub> (pin 6) to ground (pin 7)								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of line which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse working voltage	at I <sub>R</sub> = 100 nA	V <sub>RWM</sub>	-	-	28	V		
Reverse current	at $V_R = V_{RWM} = 28 V$	I <sub>R</sub>	-	-	100	nA		
Forward voltage	at $I_F = 10 \text{ mA}$	V <sub>F</sub>	0.6	0.75	0.9	V		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	32	-	40	V		
Deverse elemping veltage	at I <sub>PP</sub> = 1 A; acc. IEC 61000-4-5; T = 25 °C	V	-	37	45	V		
Reverse clamping voltage	at I <sub>PP</sub> = 3 A; acc. IEC 61000-4-5; T = 25 °C	V <sub>C</sub>	-	42	52	V		
Forward clamping voltage	at I <sub>F</sub> = 3 A; acc. IEC 61000-4-5	V <sub>F</sub>	-	-	2.2	V		
Line capacitance	at $V_R = 0$ V; f = 1 MHz	CD	-	31	40	pF		

#### Note

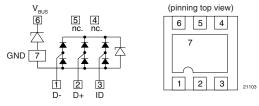
• Ratings at 25 °C, ambient temperature unless otherwise specified

#### **APPLICATION NOTE**

The VBUS053CZ-HAF is intended as an ESD-protection and transient voltage suppressor for one USB-OTG port.

The LLP75-7L package contains two separate dies which are mounted on a common ground plane (pin 7).

The high-speed data lines D-, D+ and ID, are connected to any of the pins no. 1 to 3. As long as the signal voltage on the data lines is between the ground- and the 5 V working range, the low capacitance PN-diodes offer a very high isolation to ground and to the other data lines. But as soon as any transient signal like an ESD-signal, exceeds this working range of 5 V in either the positive or negative direction, one of the PN-diodes gets into the forward mode and clamps the transient either to ground or to the avalanche break through level. An extra avalanche diode (separate die) clamps the supply line voltage (V<sub>BUS</sub> at pin 6) above the 28 V working range to ground (pin 7). Due to the "two die construction" the V<sub>BUS</sub> line has a very high isolation to the data lines. In case of a destructive transient signal, i.e. coming from a charger, the data lines will not be influenced.



#### Remark:

The input pins no. 1, 2 and 3 are symmetrical. Each of the data signals D-, D+ and ID can be connected to pin 1, 2 or 3.

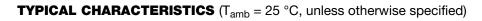
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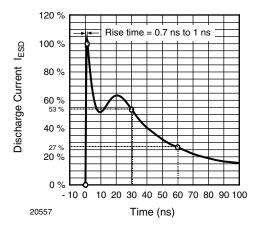
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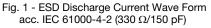


## **VBUS053CZ-HAF**

### USB-OTG BUS-Port ESD-Protection Vishay Semiconductors for $V_{BUS} = 28 V$







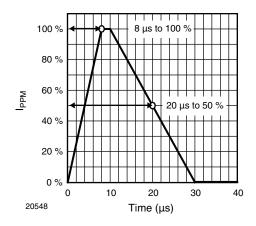


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

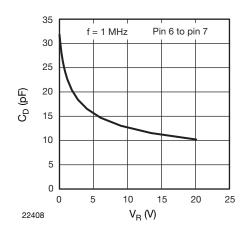


Fig. 3 - Typical Capacitance C<sub>D</sub> vs. Reverse Voltage V<sub>R</sub>

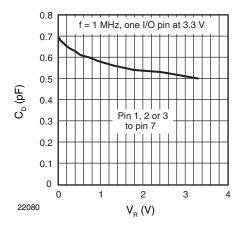


Fig. 4 - Typical Capacitance C<sub>D</sub> vs. Reverse Voltage V<sub>R</sub>

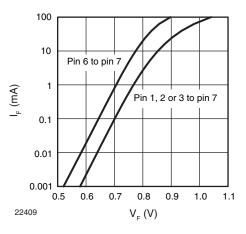


Fig. 5 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

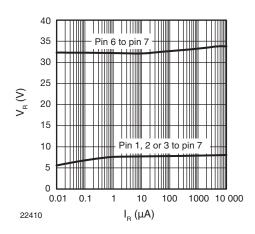


Fig. 6 - Typical Reverse Voltage V<sub>R</sub> vs.Reverse Current I<sub>R</sub>

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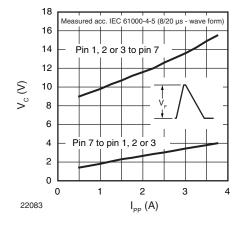
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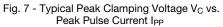
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# VBUS053CZ-HAF

### Vishay Semiconductors USB-OTG BUS-Port ESD-Protection for $V_{BUS} = 28 V$







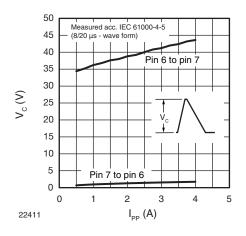


Fig. 8 - Typical Peak Clamping Voltage V<sub>C</sub> vs. Peak Pulse Current IPP

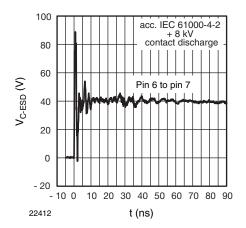


Fig. 9 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

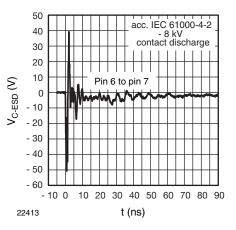


Fig. 10 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

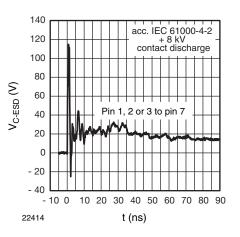


Fig. 11 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

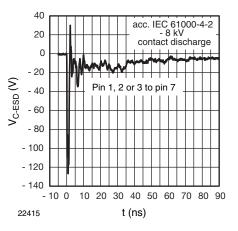
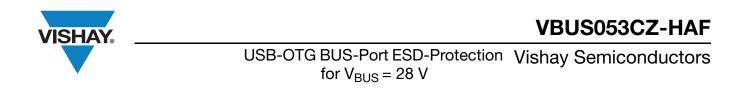


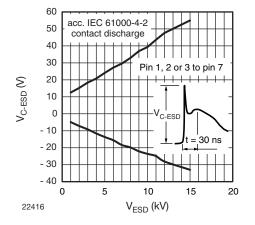
Fig. 12 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

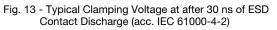
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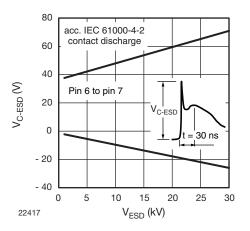
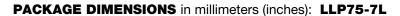
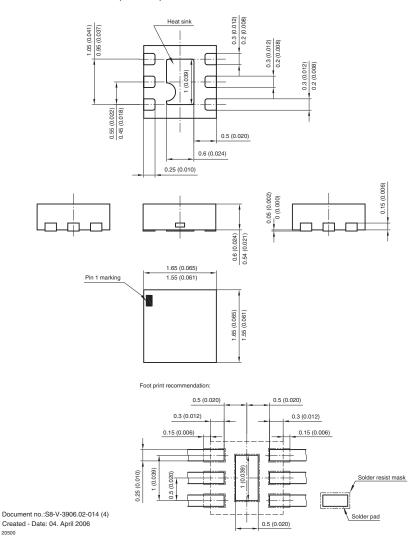


Fig. 14 - Typical Clamping Voltage at after 30 ns of ESD Contact Discharge (acc. IEC 61000-4-2)





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